

NB00615

4-8 GHZ 2W POWER AMPLIFIER

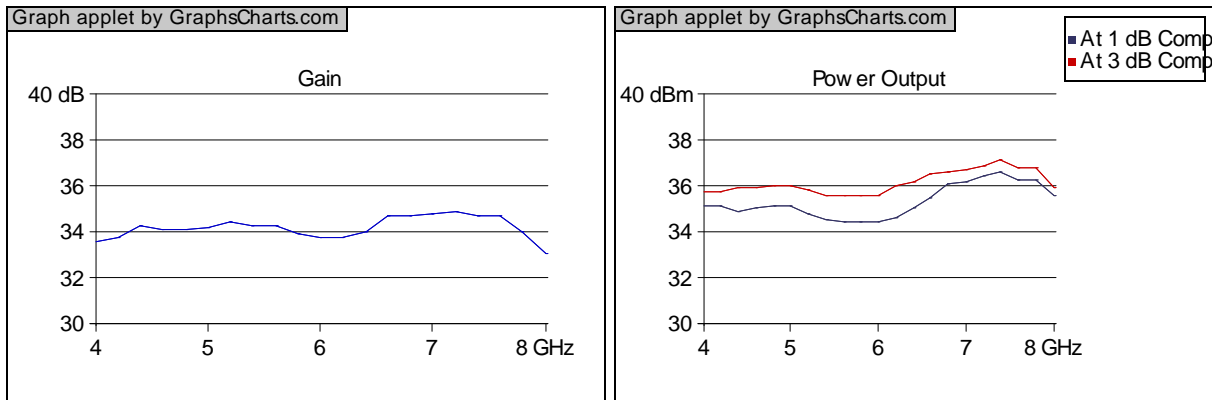
Features:

- Hybrid MIC Thin Film Process
- Field Replaceable SMA Connectors
- Reverse Bias Protection

Electrical Performance

Parameter	Min.	Typ.	Max.	Unit	Note
Frequency	4		8	GHz	
Gain	30	33	37	dB	
Gain Flatness		1	2	dB(+/-)	
Power @ 1dB Gain Compression Point	32			dBm	
Power @ 3 dB Gain Compression Point	34.5			dBm	
Output 3rd Order Intercept Point		42		dBm	
Noise Figure		4	8	dB	
VSWR Input			2		
VSWR Output			2		
Supplied Current			2	A	
DC Supply Voltage	13	15	18	V	

Typical Test Data



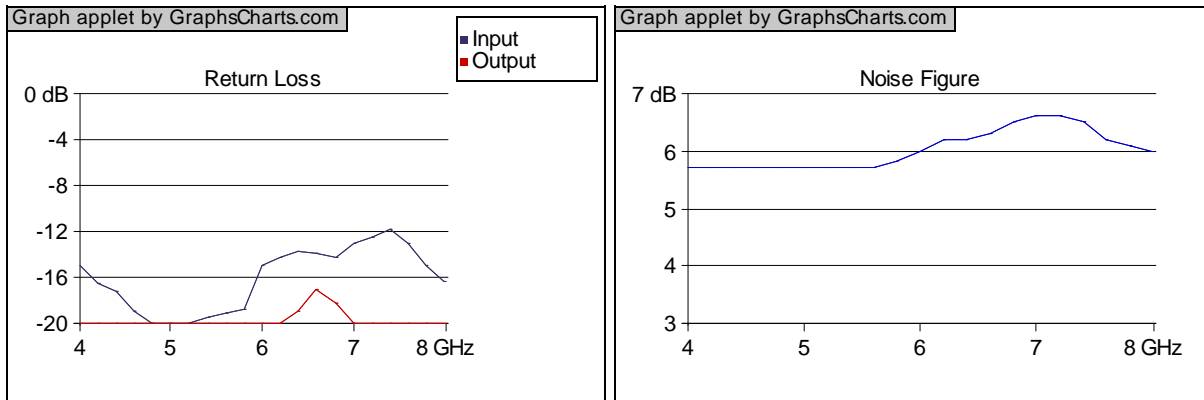
Updated: 3/19/2018



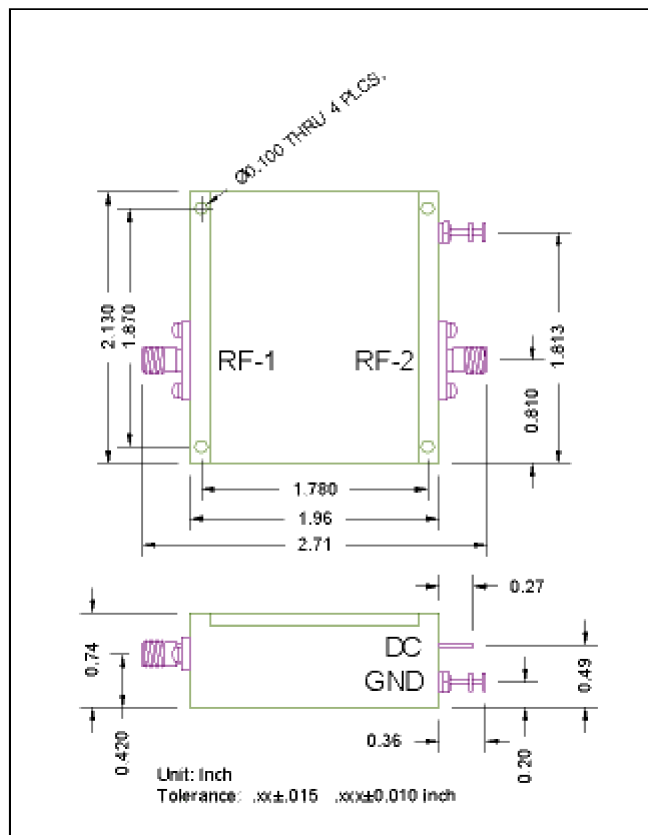
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Outline Drawing



Connector	Type	Pin #	Pin Name	In/Out	Description
RF-1	SMA-F	1	IN	I	RF SIGNAL IN
RF-2	SMA-F	1	OUT	O	RF SIGNAL OUT
DC	EMI Filter	1	+15 V	I	DC INPUT (+13 TO +18 V)

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GND GROUND LUG 1 GND O GROUND

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